OMEN Nanowire Lab Learning Materials

By completing the OMEN Nanowire Lab, users will be able to understand a) the operation of nanowire FETs, b) the effect of bandstructure on the carrier transport in nanowire FETs, and c) the effect of geometry of nanowire on the drain current characteristics in nanowire FETs.

The specific objectives of the OMEN Nanowire Lab are:

- **Physical Model**
  - Introduce the concept of:
    - Nanowire transistor
    - Tight binding model
    - Wavefunction formalism

- **Mathematical Model**
  - Understand the effects of:
    - Diameter or channel length of nanowire on carrier transport
    - Shape of nanowire on carrier transport
    - Crystal orientation of nanowire on carrier transport
    - Strain in nanowire on carrier transport

- **Computational Model**
  - Apply mathematical techniques for calculating:
    - Drain current vs gate voltage characteristics
    - Threshold voltage and subthreshold slope

- **Design and simulate** your own nanowire structures.

**Recommended Reading**

Users who are new to the concept of nanowire FETs and the simulation methods that are useful...
for understanding their characteristics should consult the following resources:

- Mark Lundstrom, Nanoscale Transistors for a basic understanding on MOS transistors.
- Joerg Appenzeller, What Promises do Nanotubes and Nanowires Hold for Future Nanoelectronics Applications?
- One-dimensional Materials
- Monica Taba, Investigation of the Electrical Characteristics of Triple-Gate FinFETs and Silicon-Nanowire FETs
- Saumitra R. Mehrotra, et al., Threshold voltage
- Mark Lundstrom, Subthreshold conduction

Demo

- Video Demo
- First Time User Guide
- Supporting Document – Limitation of the Tool at Large Gate Voltage

Theoretical Descriptions

- Mathieu Luisier, et al., Atomistic simulation of nanowires in the sp3d5s* tight-binding formalism: From boundary conditions to strain calculations, Physical Review B 74, 205323, 2006
- Mathieu Luisier, Quantum transport beyond the effective mass approximation, Ph.D. thesis, ETH, 2007
- Mathieu Luisier, Quantum Transport for Nanostructures
- Dragica Vasileska, et al., Tight-Binding Bandstructure Calculation Method

Tool Verification

- Benchmarking Top-of-the-Barrier Model by Abhijeet et al.

Examples

- First time user guide slide 15-18

Homework

- OMEN Nanowire Homework Problems

Solutions to Exercises

- Solutions to exercises are provided only to instructors!
Evaluation

- OMEN Nanowire Test Problems

Challenge

Users are challenged to integrate what they have learned about OMEN Nanowire Lab in the following module:

- solve the challenge